

	Type	Hits	Search Text	DBs	Time Stamp
1	IS&R	17	((("4859304") or ("4992137") or ("5221403") or ("5255153") or ("5275683") or ("5302241") or ("5310453") or ("5380401") or ("5382311") or ("5460684") or ("5539179") or ("5556500") or ("5583736") or ("5605603") or ("5671119") or ("4902531") or ("4859304") or ("5494522")).PN.	USPAT	2001/03/05 14:07
2	IS&R	17	((("4859304") or ("4992137") or ("5221403") or ("5255153") or ("5275683") or ("5302241") or ("5310453") or ("5380401") or ("5382311") or ("5460684") or ("5539179") or ("5556500") or ("5583736") or ("5605603") or ("5671119") or ("4902531") or ("4859304") or ("5494522")).PN.	USPAT	2001/03/05 13:46
3	BRS	15	((("4859304") or ("4992137") or ("5221403") or ("5255153") or ("5275683") or ("5302241") or ("5310453") or ("5380401") or ("5382311") or ("5460684") or ("5539179") or ("5556500") or ("5583736") or ("5605603") or ("5671119") or ("4902531") or ("4859304") or ("5494522")).PN.) and semiconductor\$ and etch\$	USPAT	2001/03/02 17:35
4	BRS	11	((("4859304") or ("4992137") or ("5221403") or ("5255153") or ("5275683") or ("5302241") or ("5310453") or ("5380401") or ("5382311") or ("5460684") or ("5539179") or ("5556500") or ("5583736") or ("5605603") or ("5671119") or ("4902531") or ("4859304") or ("5494522")).PN.) and semiconductor\$ and etch\$) and chuck	USPAT	2001/03/02 17:35
5	BRS	1	(((((("4859304") or ("4992137") or ("5221403") or ("5255153") or ("5275683") or ("5302241") or ("5310453") or ("5380401") or ("5382311") or ("5460684") or ("5539179") or ("5556500") or ("5583736") or ("5605603") or ("5671119") or ("4902531") or ("4859304") or ("5494522")).PN.) and semiconductor\$ and etch\$) and chuck) and pedestal	USPAT	2001/03/02 17:40
6	IS&R	2	((("5169408") or ("5089084")).PN.	USPAT	2001/03/02 17:40
7	BRS	2694	semiconductor\$ and ((plasma or dry or ion\$2) near etch) and (spin\$4 or rotat\$4 or revol\$5)	USPAT	2001/03/02 18:21
8	BRS	89	(semiconductor\$ and ((plasma or dry or ion\$2) near etch) and (spin\$4 or rotat\$4 or revol\$5)) and (cool\$3 near3 chamber)	USPAT	2001/03/02 18:34
9	BRS	78	(semiconductor\$ and ((plasma or dry or ion\$2) near etch) and (spin\$4 or rotat\$4 or revol\$5)) and (cool\$3 near2 chamber)	USPAT	2001/03/02 18:34
10	BRS	17	(semiconductor\$ and ((plasma or dry or ion\$2) near etch) and (spin\$4 or rotat\$4 or revol\$5)) and (cool\$3 near chamber)	USPAT	2001/03/02 18:35
11	BRS	70191	semiconductor\$ and etch\$	USPAT	2001/03/05 13:23
12	BRS	26565	(semiconductor\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)	USPAT	2001/03/05 13:25
13	BRS	2027	((semiconductor\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconductor\$ or wafer or substrate))	USPAT	2001/03/05 14:08
14	BRS	121	((semiconductor\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconductor\$ or wafer or substrate))) and clamp\$43 and cool\$3	USPAT	2001/03/05 14:17
15	BRS	30	(((((semiconductor\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconductor\$ or wafer or substrate))) and clamp\$43 and cool\$3) and chuck	USPAT	2001/03/05 13:29
16	BRS	48	(((((semiconductor\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconductor\$ or wafer or substrate))) and clamp\$43 and cool\$3) and (pedestal or chuck)	USPAT	2001/03/05 13:29

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	Type	Hits	Search Text	DBs	Time Stamp
17	BRS	1	(((((semiconduct\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate))) and clamp\$43 and cool\$3) and chuck) or (((((semiconduct\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate))) and clamp\$43 and cool\$3) and (pedestal or chuck)) or (((((semiconduct\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate))) and clamp\$43 and cool\$3) and (pedestal and chuck))) and (push near rod)	USPAT	2001/03/05 13:30
18	BRS	15	((((semiconduct\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$3 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate))) and clamp\$43 and cool\$3) and (pedestal and chuck)	USPAT	2001/03/05 13:33
19	BRS	2225	((semiconduct\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$4 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate))	USPAT	2001/03/05 15:22
20	BRS	125	((semiconduct\$ and etch\$) and ((plasma or dry or ion\$3) near etch\$)) and ((rotat\$3 or spin\$4 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate))) and clamp\$3 and cool\$3	USPAT	2001/03/05 14:18
21	BRS	26472	(rotat\$3 or spin\$4 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate)	USPAT	2001/03/05 15:40
22	BRS	2722	((rotat\$3 or spin\$4 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate)) and ((plasma or dry or ion\$3) near etch\$)	USPAT	2001/03/05 15:28
23	BRS	2225	((rotat\$3 or spin\$4 or revolv\$5) near2 (chamber or semiconduct\$ or wafer or substrate)) and ((plasma or dry or ion\$3) near etch\$)) and semiconduct\$	USPAT	2001/03/05 15:36
24	IS&R	3396	("156/345") or ("438/745") or ("438/689") or ("279/128")).CCLS.	USPAT	2001/03/05 15:37
25	BRS	31389	(rotat\$3 or spin\$4 or revolv\$5) near2 (chuck or chamber or semiconduct\$ or wafer or substrate)	USPAT	2001/03/05 15:49
26	BRS	2250	((rotat\$3 or spin\$4 or revolv\$5) near2 (chuck or chamber or semiconduct\$ or wafer or substrate) ) and semiconduct\$ and ((plasma or dry or ion\$3) near etch\$)	USPAT	2001/03/05 15:52
27	BRS	162	((rotat\$3 or spin\$4 or revolv\$5) near2 (chuck or chamber or semiconduct\$ or wafer or substrate) ) and semiconduct\$ and ((plasma or dry or ion\$3) near etch\$)) and (((("156/345") or ("438/745") or ("438/689") or ("279/128")).CCLS.))	USPAT	2001/03/05 15:54
28	BRS	88	((rotat\$3 or spin\$4 or revolv\$5) near2 (chuck or chamber or semiconduct\$ or wafer or substrate) ) and semiconduct\$ and ((plasma or dry or ion\$3) near etch\$)) and (((("156/345") or ("438/745") or ("438/689") or ("279/128")).CCLS.)) and cool\$3	USPAT	2001/03/05 15:55
29	BRS	23	((rotat\$3 or spin\$4 or revolv\$5) near2 (chuck or chamber or semiconduct\$ or wafer or substrate) ) and semiconduct\$ and ((plasma or dry or ion\$3) near etch\$)) and (((("156/345") or ("438/745") or ("438/689") or ("279/128")).CCLS.)) and cool\$3) and chuck	USPAT	2001/03/05 16:13
30	IS&R	1	("5169408").PN.	USPAT	2001/03/05 16:13